



TAYCHIPST

LOW VF SCHOTTKY BARRIER DIODE

SX33L

30V 3.0A

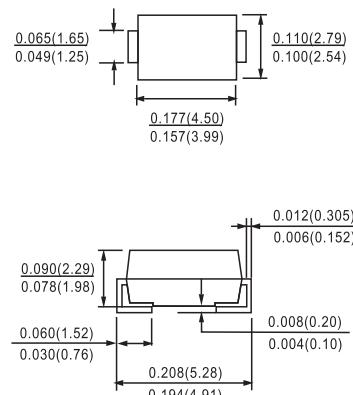
FEATURES

- Low forward voltage drop, low reverse current
- High Efficiency
- In compliance with EU RoHS 2002/95/EC directives

MECHANICAL DATA

- Case: JEDEC DO-214AC molded plastic
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Standard packaging: 12mm tape (EIA-481)
- Weight: 0.0023 ounce, 0.0679 gram

DO-214AC(SMA)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$)**

PARAMETER	SYMBOL	LIMITS	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	30	V
Maximum Average Rectified Forward Current	I_o	3	A
Peak Surge Forward Current	I_{FSM}	75	A
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$ $R_{\theta JL}$	100 20	$^\circ C/W$
Operating Junction Temperature Range	T_J	-55 to +125	$^\circ C$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ C$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Instantaneous forward voltage (Note 2)	V_F	$I_F=1A$ $I_F=2A$ $I_F=3A$ $T_J=25^\circ C$	-	0.29 0.32 0.35	0.31 0.35 0.37	V
		$I_F=1A$ $I_F=2A$ $I_F=3A$ $T_J=125^\circ C$	-	0.17 0.21 0.26	- - -	V
		$V_R=21V$ $T_J=25^\circ C$ $T_J=125^\circ C$	-	0.3 90	0.5 -	mA
Reverse current	I_R		-	0.8 160	1 -	mA

NOTES:

1. Mounted on P.C. Board with 25mm² copper pad areas.
2. Pulse Test with PW =300μsec, 1% Duty Cycle.



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RATINGS AND CHARACTERISTIC CURVES

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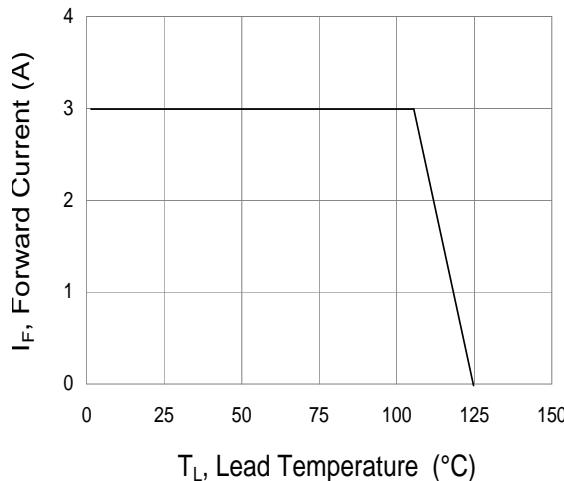


Fig.1 Forward Current Derating Curve

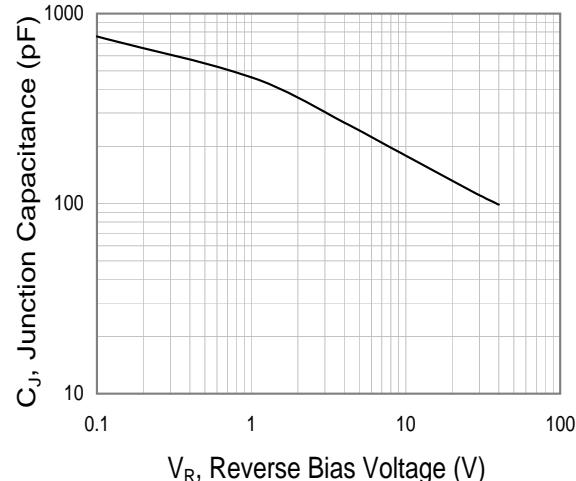


Fig.2 Typical Junction Capacitance

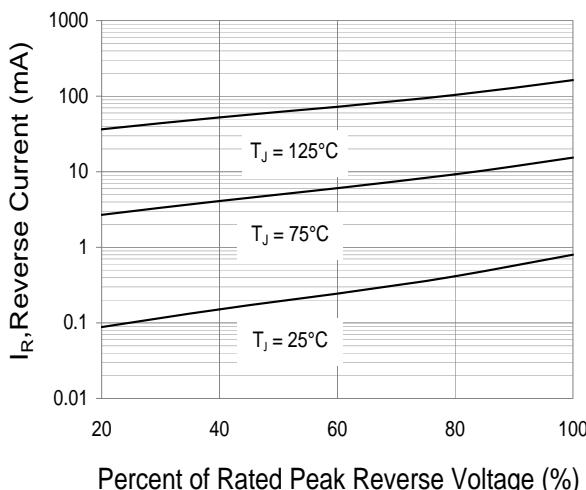


Fig.3 Typical Reverse Characteristics

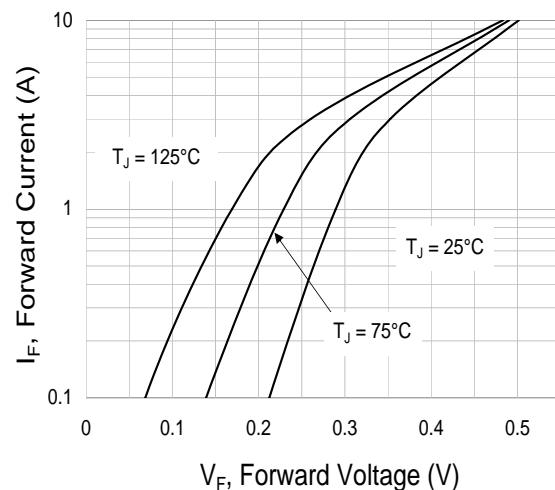


Fig.4 Typical Forward Characteristics